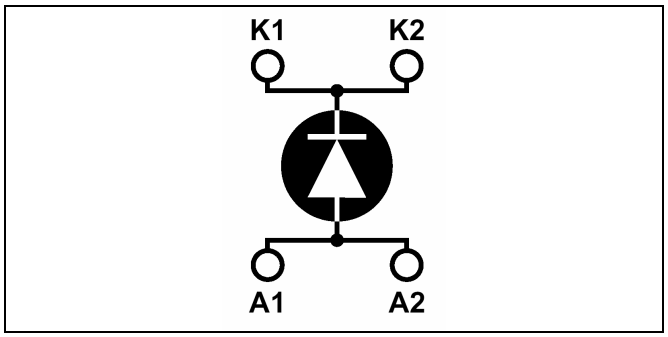
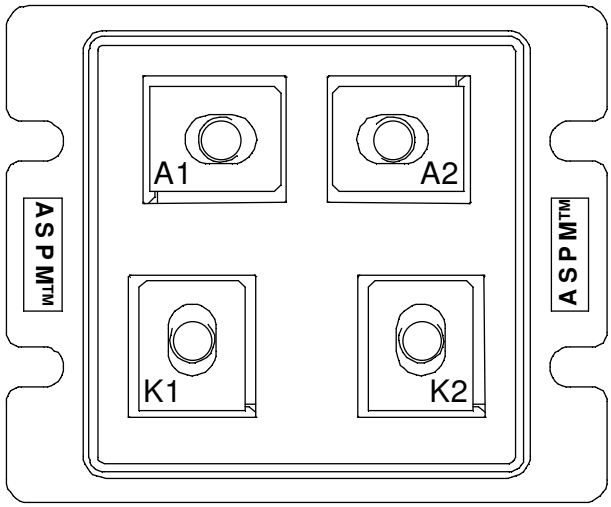
Single diode Power Module

V_{CES} = 200V
I_C = 500A @ Tc = 80°C



Application

- Anti-Parallel diode
  - Switchmode Power Supply
  - Inverters
- Snubber diode
- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High speed rectifiers
- Electric vehicles



Features

- Ultra fast recovery times
- Soft recovery characteristics
- Very low stray inductance
- High blocking voltage
- High current
- Low leakage current

Benefits

- Low losses
- Low noise switching
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance

Absolute maximum ratings

Symbol	*Parameter*			*Max ratings*	*Unit*
V_R	Maximum DC reverse Voltage			200	V
V_{RRM}	Maximum Peak Repetitive Reverse Voltage				
$I_{F(AV)}$	Maximum Average Forward Current	Duty cycle = 50%	T_c = 25°C	500	A
			T_c = 80°C	500	
$I_{F(RMS)}$	RMS Forward Current			850	
I_{FSM}	Non-Repetitive Forward Surge Current		T_j = 25°C	5000	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handing Procedures Should Be Followed.

Electrical Characteristics

All ratings @ T_j = 25°C unless otherwise specified

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_F	Diode Forward Voltage	I_F = 500A				1.1	V
		I_F = 1000A			1.25		
		I_F = 500A	T_j = 150°C			0.95	
I_{RM}	Maximum Reverse Leakage Current	V_R = 200V	T_j = 25°C			2500	µA
			T_j = 150°C			5000	
C_T	Junction Capacitance	V_R = 200V			1000		pF
L_S	Series Inductance	Lead to Lead 5mm from Base			30	40	nH

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
t_{rr1}	Reverse Recovery Time	I_F=1A,V_R=30V di/dt = 15A/µs	T_j = 25°C		70		ns
t_{rr2}		I_F = 500A V_R = 100V di/dt=800A/µs	T_j = 25°C		70		
t_{rr3}			T_j = 100°C		150		
t_{fr1}	Forward Recovery Time	I_F = 500A V_R = 100V di/dt=800A/µs	T_j = 25°C		250		ns
t_{fr2}			T_j = 100°C		250		
I_{RRM1}	Reverse Recovery Current		T_j = 25°C			50	A
I_{RRM2}			T_j = 100°C			120	
Q_{rr1}	Reverse Recovery Charge		T_j = 25°C		4.9		µC
Q_{rr2}			T_j = 100°C		22		
V_{fr1}	Forward Recovery Voltage		T_j = 25°C		15		V
V_{fr2}			T_j = 100°C		15		
$d_{IM/dt}$	Rate of Fall of Recovery Current		T_j = 25°C		1200		A/µs
			T_j = 100°C		1800		

Thermal and package characteristics

Symbol	Characteristic			Min	Typ	Max	Unit
R_{thJC}	Junction to Case					0.08	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, I isol<1mA, 50/60Hz			2500			V
T_J	Operating junction temperature range			-40		150	°C
T_{STG}	Storage Temperature Range			-40		125	
T_C	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M5	2.5		3.5	N.m
		For terminals	M6	3		4	
Wt	Package Weight					250	g

Package outline